

SRV05-4_054

Low Capacitance Array for Surge & ESD Protection

The SRV05-4_054 has a low typical capacitance of 3.0pF and operates with virtually no insertion loss to 2.0GHz. This makes the device ideal for protection of high-speed data lines such as USB 2.0, Firewire, DVI, and gigabit Ethernet interfaces. The low capacitance array configuration allows the user to protect four high-speed data or transmission lines. The low inductance construction minimizes voltage overshoot during high current surges. It may be used to meet the ESD immunity requirements of IEC61000-4-2, Level 4 ($\pm 15\text{kV}$ air, $\pm 8\text{kV}$ contact discharge).

It has been specifically designed to protect sensitive components which are connected to high-speed data and transmission lines from overvoltage caused by ESD(electrostatic discharge), CDE (Cable Discharge Events),and lightning.

Features

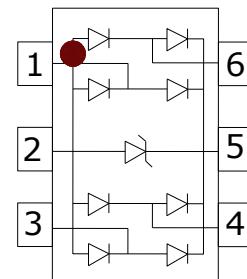
- Protects four I/O lines and one Vcc line
- Low capacitance
- Working voltages : 5V
- Low leakage current
- Response Time is < 1 ns
- Low capacitance (<4.5pF) for high-speed interfaces
- No insertion loss to 2.0GHz
- Meets MSL 1 Requirements
- Solid-state silicon avalanche technology
- ROHS compliant
- WeiPan technology



Main applications

- Digital Visual Interface (DVI)
- 10/100/1000 Ethernet
- USB 1.1/2.0/OTG
- IEEE 1394 Firewire Ports
- Projection TV Monitors and Flat Panel Displays
- Notebook Computers
- Set Top Box
- Projection TV

SOT-23-6L



Protection solution to meet

- IEC61000-4-2 (ESD) $\pm 15\text{kV}$ (air), $\pm 8\text{kV}$ (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)
- IEC61000-4-5 (Lightning) 20A (8/20 μs)

Ordering Information

| Device | Marking | Qty per Reel | Reel Size |
|-------------|---------|--------------|-----------|
| SRV05-4_054 | 054 | 3000 | 7 Inch |

Maximum ratings (Tamb=25°C Unless Otherwise Specified)

| Parameter | Symbol | Value | Unit |
|--|------------------|---------------|-------|
| Peak Pulse Power (tp=8/20μs waveform) | P _{PPP} | 300 | Watts |
| Peak Pulse Current(tp=8/20μs waveform) | I _{PP} | 20 | A |
| ESD Rating per IEC61000-4-2: | Contact | 30 | KV |
| | Air | 30 | |
| Lead Soldering Temperature | T _L | 260 (10 sec.) | °C |
| Operating Temperature Range | T _J | -55 ~ 150 | °C |
| Storage Temperature Range | T _{STG} | -55 ~ 150 | °C |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

*Other voltages may be available upon request.

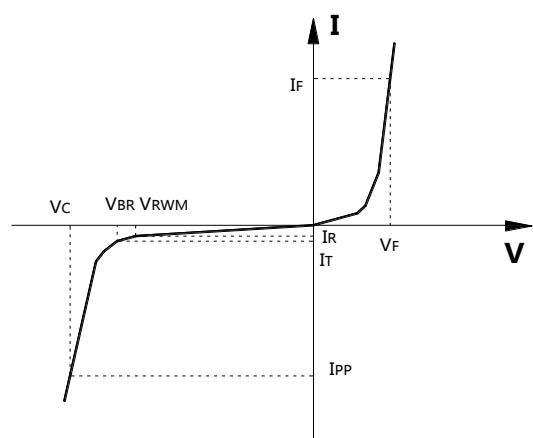
1. Non-repetitive current pulse, per Figure 1.

Electrical characteristics (Tamb=25°C Unless Otherwise Specified)

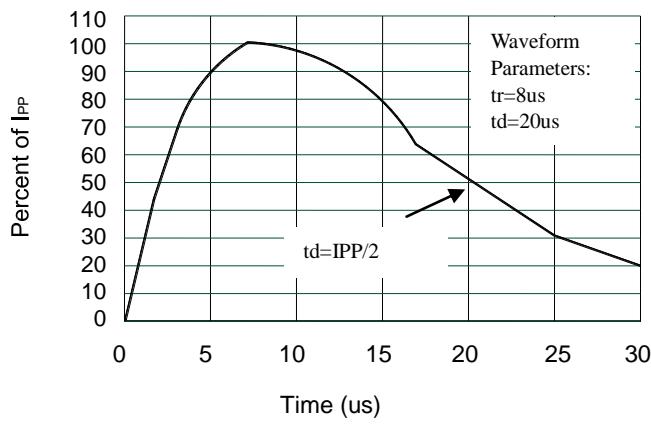
| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|------------------|---------------------------|--|------|------|------|-------|
| V _{RWM} | Reverse Working Voltage | Any I/O to Ground | | | 5.0 | V |
| V _{BR} | Reverse Breakdown Voltage | IT = 1mA, Any I/O to Ground | 6.0 | | | V |
| I _R | Reverse Leakage Current | V _{RWM} = 5V, Any I/O to Ground | | | 2.5 | μA |
| V _F | Diode Forward Voltage | IF = 15mA | | 0.85 | 1.2 | V |
| V _C | Clamping Voltage | I _{PP} = 1A, tp =8/20μs, any I/O pin to Ground | | | 12.7 | V |
| | | I _{PP} = 5A, tp =8/20μs, any I/O pin to Ground | | | 17.5 | V |
| I _{PP} | Peak Pulse Current | tp =8/20μs | | | 20 | A |
| C _J | Junction Capacitance | V _R = 0V, f = 1MHz, between I/O pins | | 1.7 | 3.0 | pF |
| | | V _R = 0V, f = 1MHz, any I/O pin to Ground | | 2.8 | 4.5 | pF |

Junction capacitance is measured in VR=0V,F=1MHz

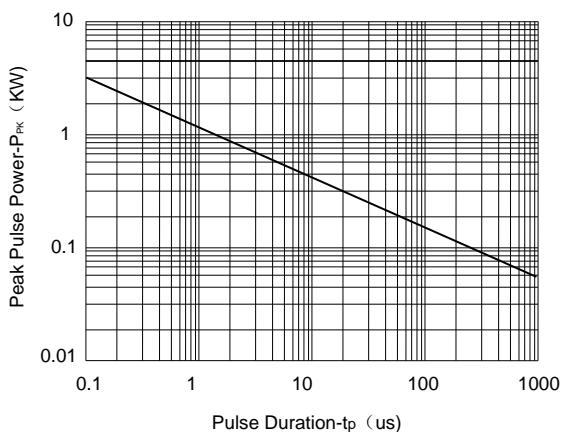
| Symbol | Parameter |
|------------------|-------------------------------------|
| V _{RWM} | Working Peak Reverse Voltage |
| V _{BR} | Breakdown Voltage @ IT |
| V _C | Clamping Voltage @ IPP |
| I _T | Test Current |
| I _{RM} | Leakage current at V _{RWM} |
| I _{PP} | Peak pulse current |
| C _O | Off-state Capacitance |
| C _J | Junction Capacitance |



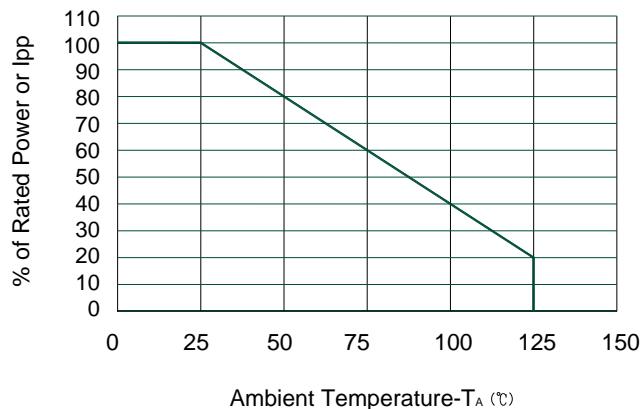
Typical electrical characterist applications



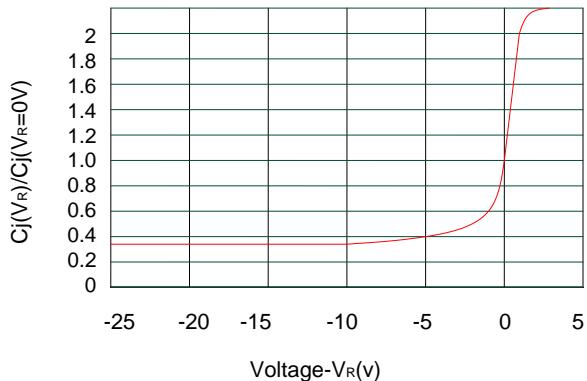
Pulse Waveform



Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve



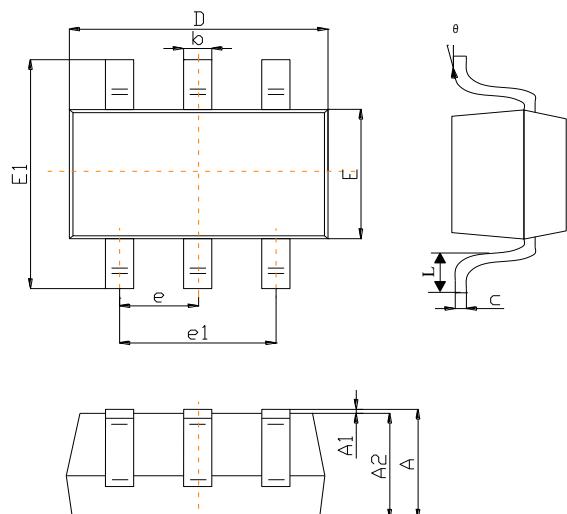
Junction Capacitance vs. Reverse Voltage

Package Information

SOT23-6L

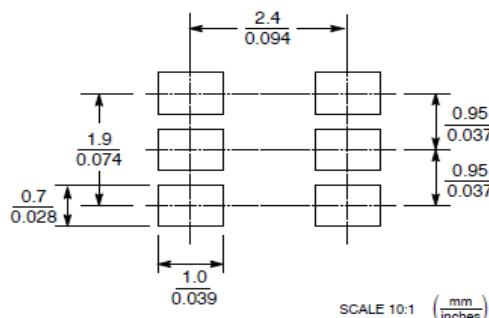
Mechanical Data

- Case: SOT23-6L
- Case Material: Molded Plastic. UL Flammability

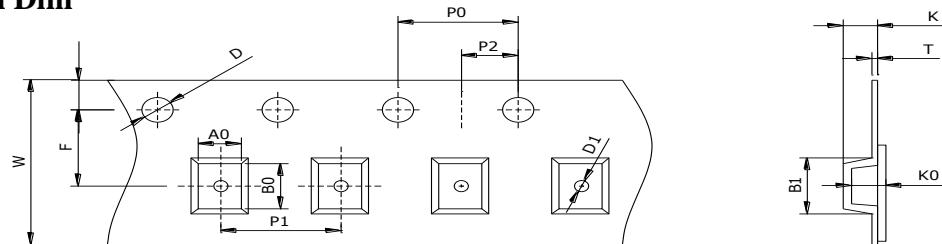


| DIM | Millimeters | | Inches | |
|-----|-------------|-------|------------|-------|
| | Min | Max | Min | Max |
| A | 1.050 | 1.250 | 0.041 | 0.049 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.100 | 0.200 | 0.004 | 0.008 |
| D | 2.820 | 3.020 | 0.111 | 0.119 |
| E | 1.500 | 1.700 | 0.059 | 0.067 |
| E1 | 2.650 | 2.950 | 0.104 | 0.116 |
| e | 0.950(BSC) | | 0.037(BSC) | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.300 | 0.600 | 0.012 | 0.024 |
| θ | 0 | 8° | 0 | 8° |

Recommended Pad outline



SOT23-6L Reel Dim



| Package | Chip Size | Pocket Size B0×A0×K0(mm) | Tape Width | Reel Diameter | Quantity Per Reel | P0 | P1 |
|----------|----------------|-----------------------------|---------------|---------------|-------------------|-----|-----|
| SOT23-6L | 3.00×2.90×1.20 | 3.20×3.10×1.40 | 8mm | 178mm(7") | 3000 | 4mm | 4mm |
| D0 | D1 | E | F | K | T | W | |
| 1.5mm | 1.0mm | 1.75mm | 3.5mm | 1.25mm | 0.2mm | 8mm | |